



## Features

- Active Mixer with Conversion Gain
- Integrated LO and IF Drivers
- Excellent Linearity
- Broadband 50  $\Omega$  Impedance on all Ports
- Low LO-RF Leakage
- Differential or Single Ended Inputs

## Benefits

- Small and Thin 16-pin SSOP Package with Exposed Paddle
- Few External Components
- Fully ESD Protected

## Application

- DCS/PCS/TDMA and CDMA2000 Transmitter
- Other Digital Communication Applications
- High Performance RF Instrumentation

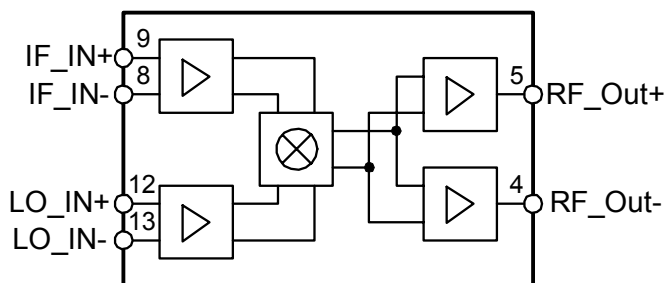
## Description

The ATR0786 is a high linearity active mixer which is manufactured using Atmel's advanced Silicon Germanium technology for the use in a variety of high performance requiring RF systems such as digital communications.

This mixer features a frequency range of 1800 MHz to 2100 MHz. It operates from a single 5 V supply and provides 16 dB of conversion gain while requiring only 0 dBm input to the integrated LO driver. An IF and an LO amplifier is also included.

The ATR0786 incorporates internal matching on each RF, IF and LO port to enhance ease of use and to reduce the external components required. The RF and LO inputs can be driven differentially or single ended.

Figure 1. Block Diagram



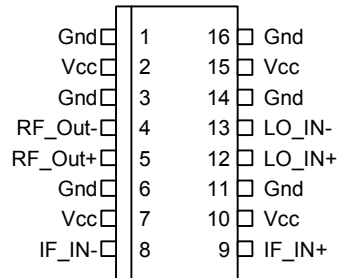
**High Linearity  
Active Transmit  
Mixer for  
1800 MHz to  
2100 MHz**

**ATR0786**



## Pin Configuration

Figure 2. Pinning TSSOP16



## Pin Description

Pin	Symbol	Function
1	GND	Ground
2	Vcc	Supply voltage
3	GND	Ground
4	RF_OUT-	Negative RF output; nominal DC voltage is 2.3 V; (internally biased) input should be AC-coupled
5	RF_OUT+	Positive RF output; nominal DC voltage is 2.3 V; (internally biased) input should be AC-coupled
6	GND	Ground
7	Vcc	Supply voltage
8	IF_IN-	Negative IF input; nominal DC voltage is 2.3 V, provided through off chip inductors
9	IF_IN+	Positive IF input; nominal DC voltage is 2.3 V, provided through off chip inductors
10	Vcc	Supply voltage
11	GND	Ground
12	LO_IN+	Negative local oscillator input; nominal DC voltage is 2.3 V; (internally biased) input should be AC-coupled
13	LO_IN-	Positive local oscillator input; nominal DC voltage is 2.3 V; (internally biased) input should be AC-coupled
14	GND	Ground
15	Vcc	Supply voltage
16	GND	Ground
Paddle		Device Ground and heat sink, requires good thermal path; RF reference plane

## Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltages, no RF applied	$V_{CC}$	-0.5 to +5.5	V
LO input signals	LO_IN-; LO_IN+	+10.0	dBm
IF input signals	IF_IN-; IF_IN+	+10.0	dBm
Operating case temperature	$T_C$	-40 to +85	°C
Storage temperature	$T_{STG}$	-55 to +150	°C

## Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	$R_{thJA}$	25	K/W

## Electrical Characteristics

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions:  $V_{CC} = +5.0$  V,  $T_{amb} = 25^\circ\text{C}$ ;  $P_{LO} = 0$  dBm; IF = 200 MHz;  $P_{IF} = -20$  dBm

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
<b>General Performance</b>									
	Supply voltage			$V_{CC}$	4.75	5.0	5.25	V	
	Supply current			$I_{CC}$		200		mA	
	LO drive	Matched to 50 $\Omega$			-3	0	+3	dBm	
	LO, IF, RF return loss	Matched to 50 $\Omega$				14		dB	

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## RF Electrical Characteristics (1800 MHz to 2000 MHz)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions:  $V_{CC} = +5.0$  V,  $T_{amb} = 25^\circ\text{C}$ ;  $P_{LO} = 0$  dBm; IF = 200 MHz;  $P_{IF} = -20$  dBm

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
<b>Mixer RF Performance</b>									
	RF frequency			$f_{RF}$	1800		2000	MHz	
	LO frequency			$f_{LO}$	1600		1800	MHz	
	IF frequency			$f_{IF}$	30	200	400	MHz	
	Conversion gain			G	15	17	19	dB	
	SSB noise figure			NF		9.5	11.0	dB	
	Output IP3	IF1 = IF2 = -20 dBm/tone, 1 MHz spacing		OIP3	20	24		dBm	
	Output P1dB			P1dB	8	11		dBm	
	Leakage (LO-RF)					-20	-10	dBm	
	Leakage (LO-IF)					-45	-35	dBm	

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## RF Electrical Characteristics (2000 MHz to 2100 MHz)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions:  $V_{CC} = +5.0\text{ V}$ ,  $T_{amb} = 25^\circ\text{C}$ ;  $P_{LO} = 0\text{ dBm}$ ;  $IF = 200\text{ MHz}$ ;  $P_{IF} = -20\text{ dBm}$

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
<b>Mixer RF Performance</b>									
	RF frequency			$f_{RF}$	2000		2100	MHz	
	LO frequency			$f_{LO}$	1800		2000	MHz	
	IF frequency			$f_{IF}$	30	200	400	MHz	
	Conversion gain			G	13	16	18	dB	
	SSB noise figure			NF		9.5	11.0	dB	
	Output IP3	IF1 = IF2 = -20 dBm/tone, 1 MHz spacing		OIP3	17	21		dBm	
	Output P1dB			P1dB	6	9		dBm	
	Leakage (LO-RF)					-20	-10	dBm	
	Leakage (LO-IF)					-45	-35	dBm	

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## Typical Performance

Figure 3. Conversion Gain versus Frequency + Temperature

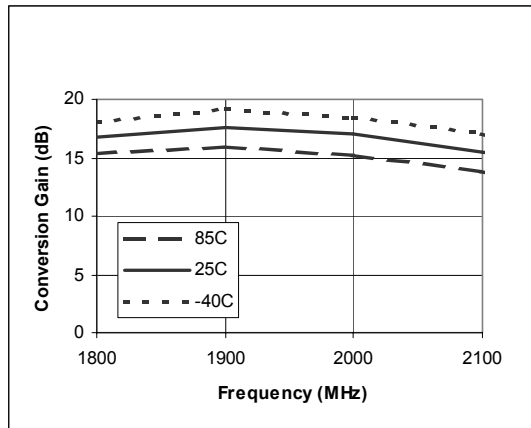


Figure 4. Output IP3 versus Frequency + Temperature

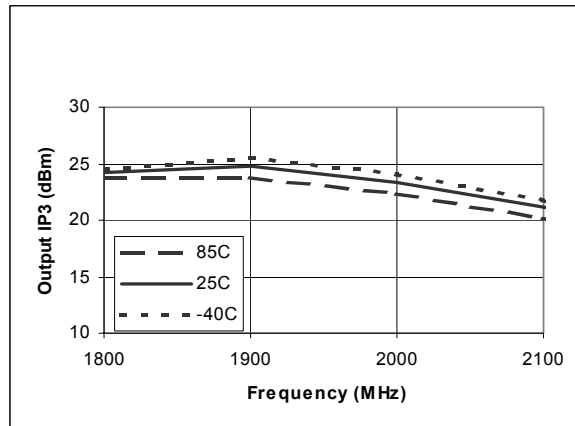


Figure 5. Output IP3 versus Frequency + LO Drive

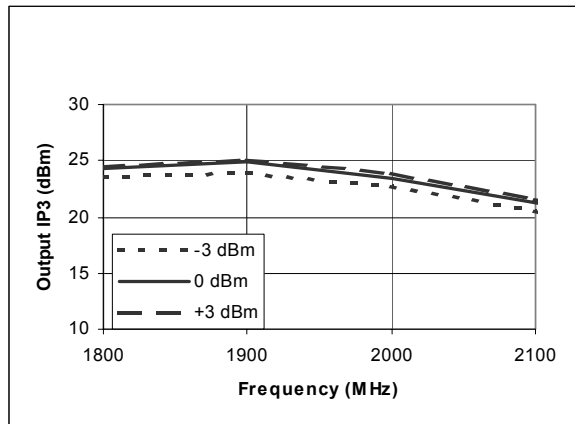
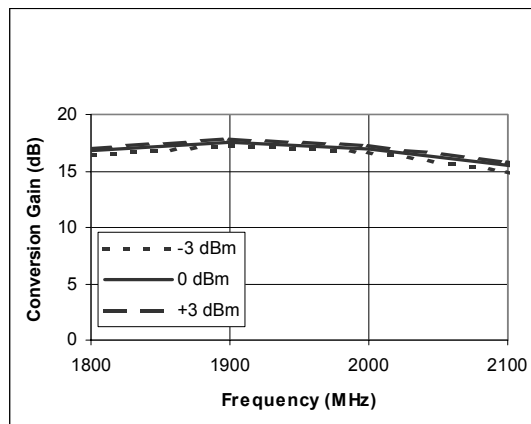
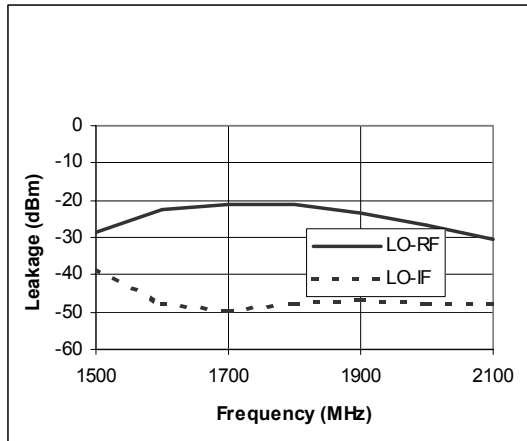


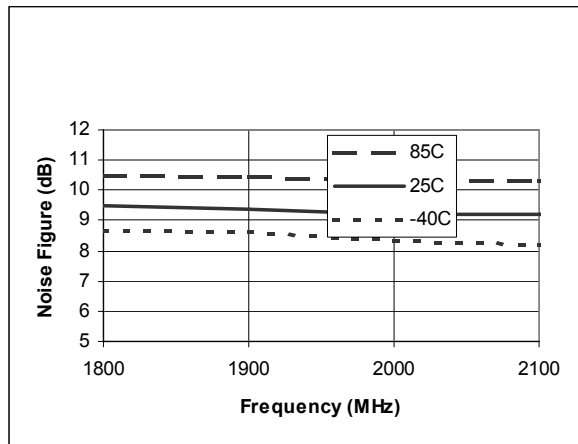
Figure 6. Conversion Gain versus Frequency + LO Drive



**Figure 7. Leakages versus Frequency**



**Figure 8. Noise Figure versus Frequency + Temperature**



**Figure 9. RF and LO Return Loss versus Frequency**

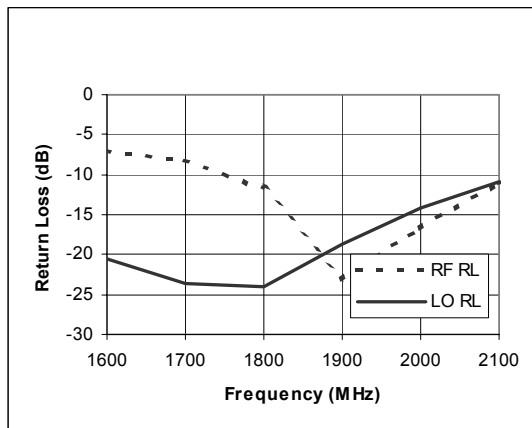


Figure 10. Output P1dB versus Frequency + Temperature

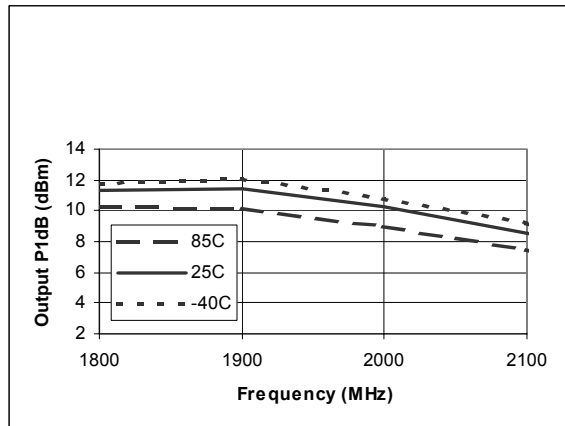


Figure 11. IF Return Loss versus Frequency

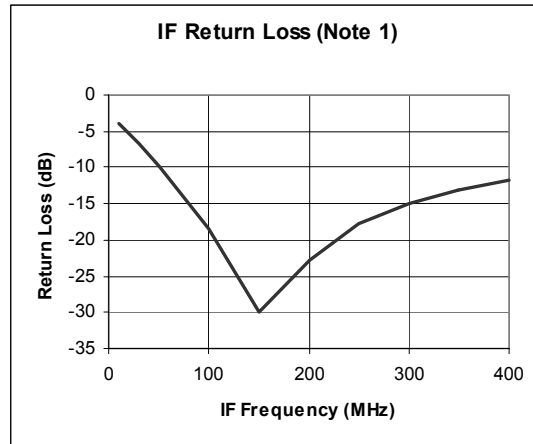
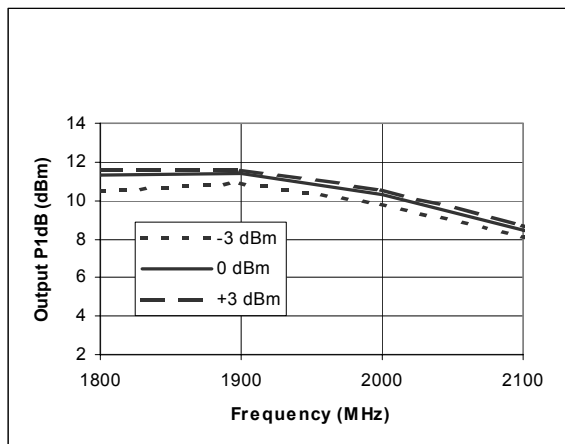
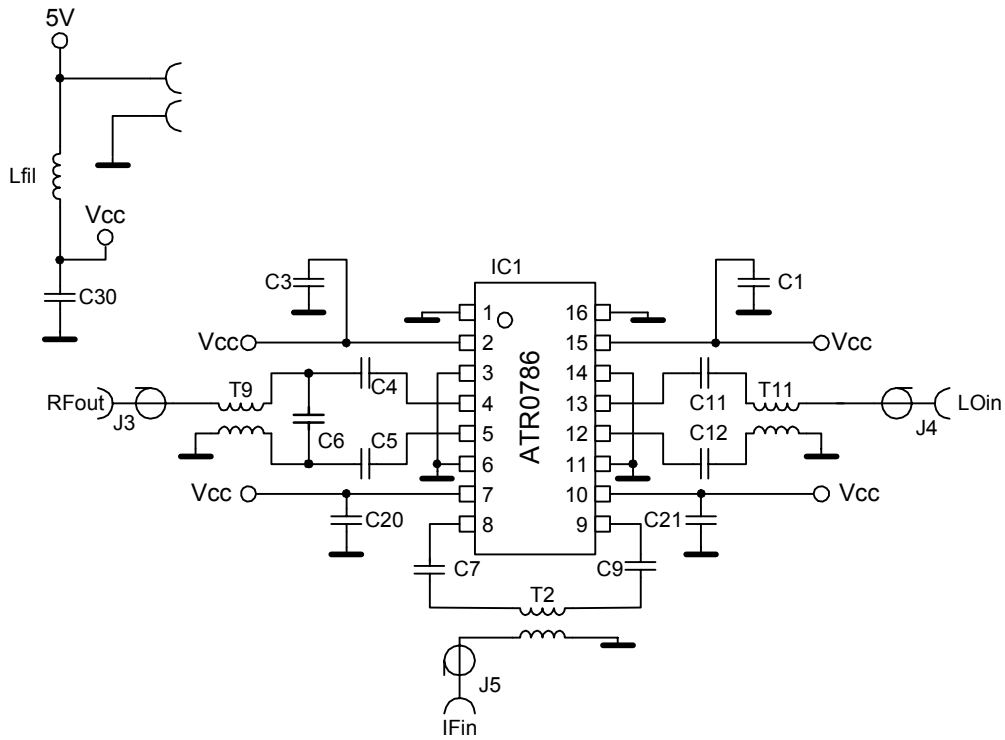


Figure 12. Output P1dB versus Frequency + LO Drive



**Figure 13. Demo Board Schematic**



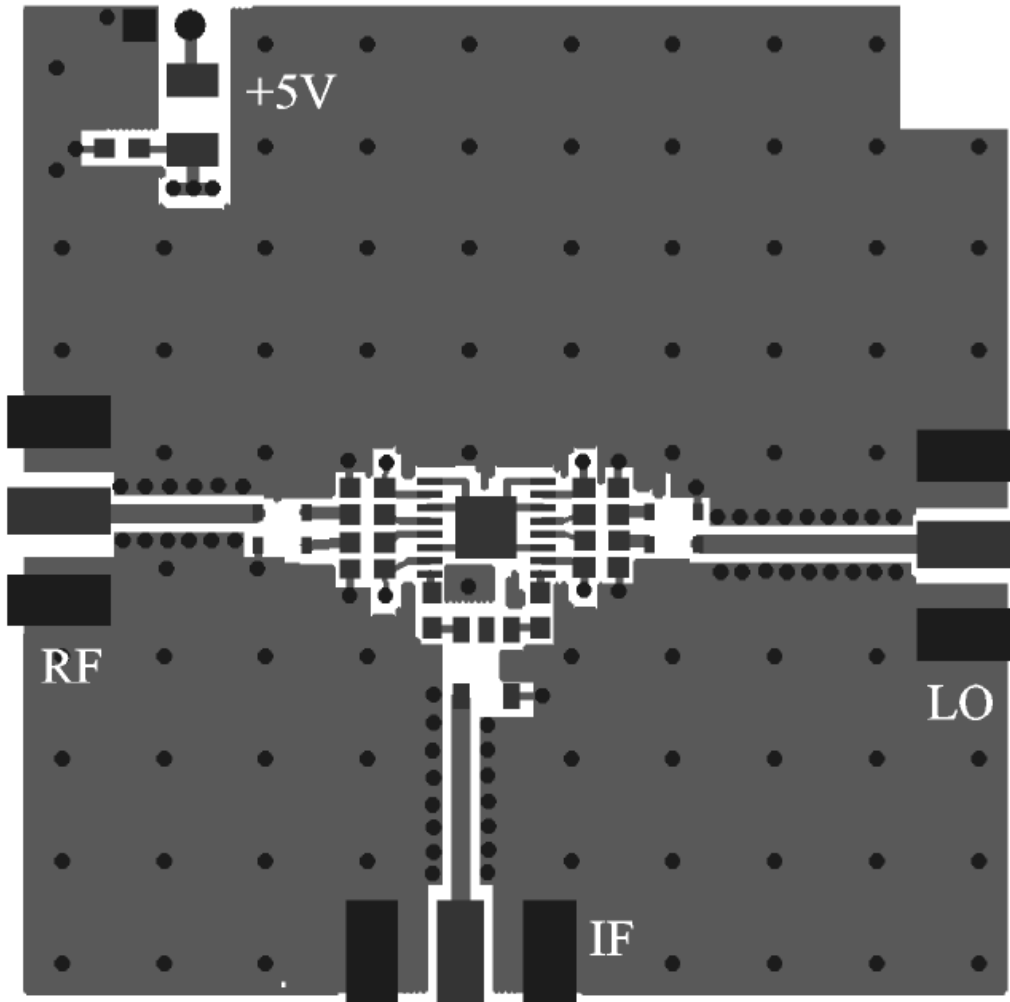
**Bill of Material of Demo Board**

Parameters	Test Conditions	Pin	Symbol	Min.	Typ.
Highly linear active mixer		Atmel	ATR0786		16-pin TSSOP
Capacitor	C7, C9			100 pF	0603
Capacitor	C1, C3, C20, C21, C30			6.8 pF	0603
Capacitor	C11, C12			4.7 pF	0603
Capacitor	C4, C5			3.3 pF	0603
Inductor	Lfil	Würth Elektronik	74476401	1 $\mu$ H	1210
Capacitor	C6			1.2 pF	0603
Transformer	T9, T11	Panasonic	EHF-FD1619		
Transformer	T2	Mini-Circuits®	TC1-1		
RF connector		Johnson Components	142-0701-851		SMA

Note: 1. Other sizes are possible.

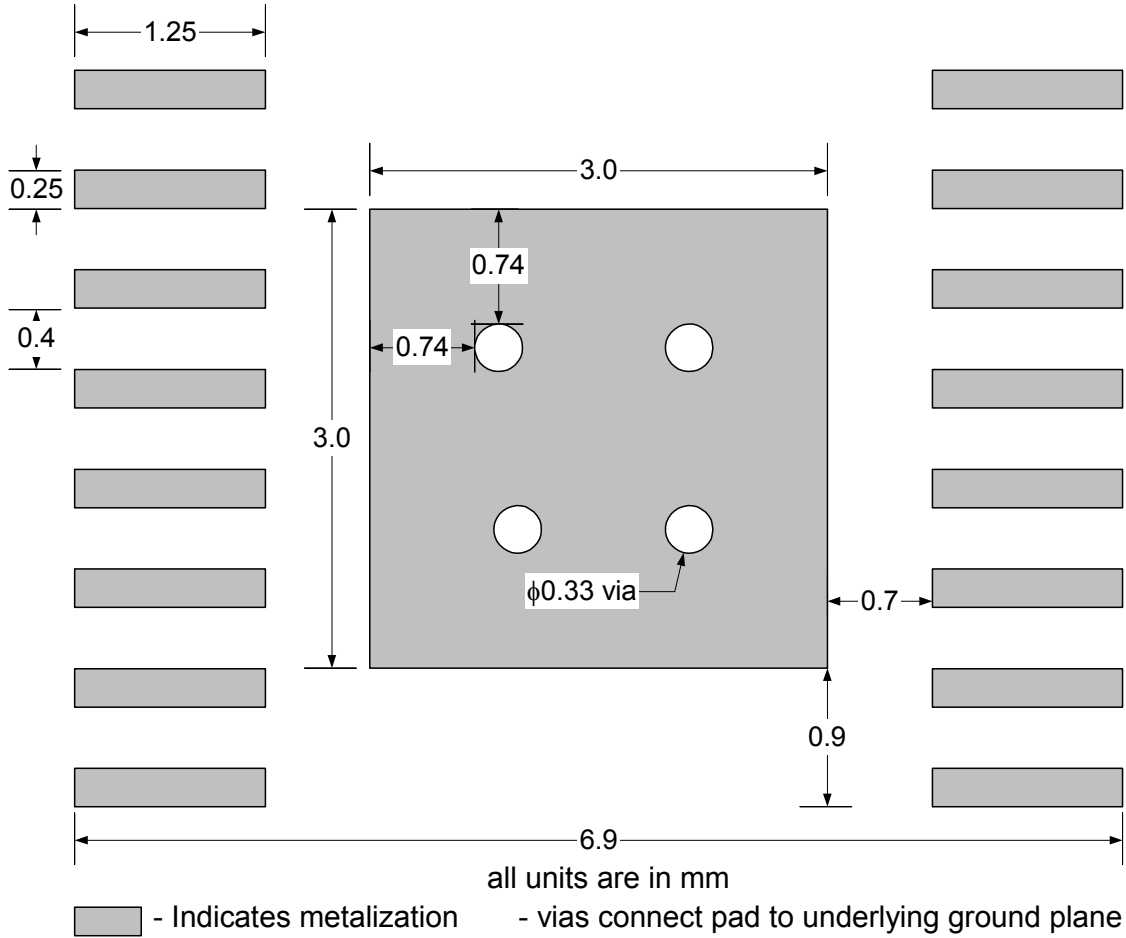


Figure 14. Demo Test Board



## Recommended Package Footprint

- Notes: 1. Only ground signal traces are allowed directly under the package  
 2. Primary dimensions are in millimeter alternate dimensions are in inches



Remark: Heatslug must be soldered to GND!

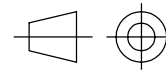
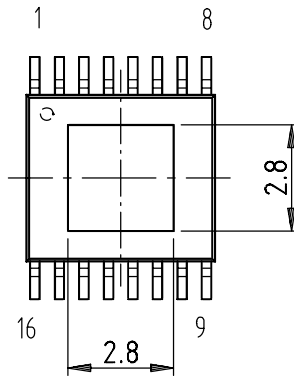
Plugging of the ground vias under the heat slug is also recommended to avoid soldering problems.

### Ordering Information

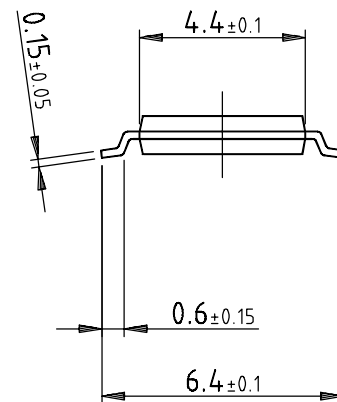
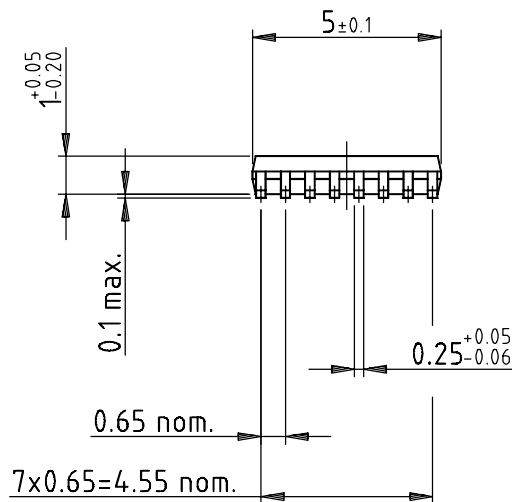
Extended Type Number	Package	Remarks
ATR0786	TSSOP16	5.0 mm × 6.4 mm

### Package Information

Package: SSOP16  
 ( acc. JEDEC SMALL OUTLINE No. MO-153 )  
 Dimensions in mm



technical drawings  
 according to DIN  
 specifications



Drawing-No.: 6.543-5079.01-4  
 Issue: 1; 10.07.01



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